

# 2SC2258(A)

Rev.E Mar.-2016

## 描述 / Descriptions

TO-126F 塑封封装 NPN 半导体三极管。Silicon NPN transistor in a TO-126F Plastic Package.

## 特征 / Features

耐压高,  $f_T$  高。

High  $V_{CEO}$ , high  $f_T$ .

## 用途 / Applications

用于普通高压放大, 彩电色度输出。

High voltage general amplifier, TV video output amplifier.

## 内部等效电路 / Equivalent Circuit



## 引脚排列 / Pinning



PIN1 : Emitter

PIN 2 : Collector

PIN 3 : Base

## 放大及印章代码 / $h_{FE}$ Classifications & Marking

见印章说明。See Marking Instructions.

**极限参数 / Absolute Maximum Ratings(Ta=25°C)**

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit	
Collector to Base Voltage	V <sub>CBO</sub>	2SC2258	250	V
		2SC2258A	300	
Collector to Emitter Voltage	V <sub>CEO</sub>	2SC2258	250	V
		2SC2258A	300	
Emitter to Base Voltage	V <sub>EBO</sub>	7.0	V	
Collector Current – Continuous(Pulse)	I <sub>CP</sub>	150	mA	
Collector Current - Continuous	I <sub>C</sub>	100	mA	
Collector Power Dissipation	P <sub>C</sub>	1.0	W	
Collector Power Dissipation*	*P <sub>C</sub> (T <sub>C</sub> =25°C)	4.0*	W	
Junction Temperature	T <sub>j</sub>	150	°C	
Storage Temperature Range	T <sub>stg</sub>	-55~150	°C	

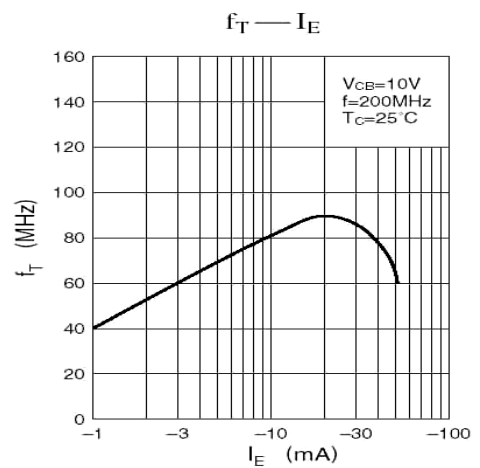
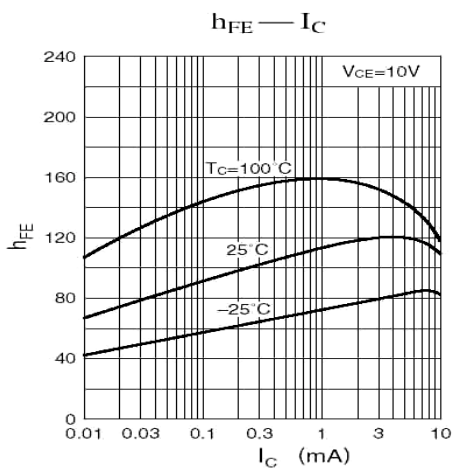
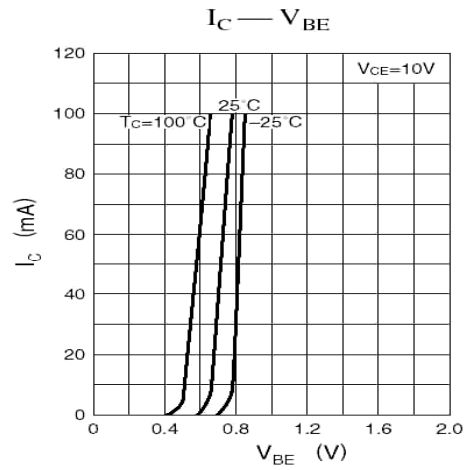
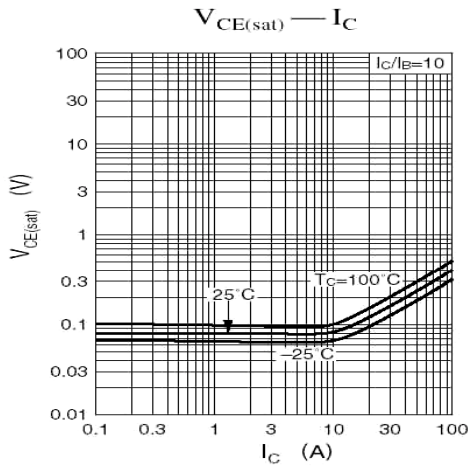
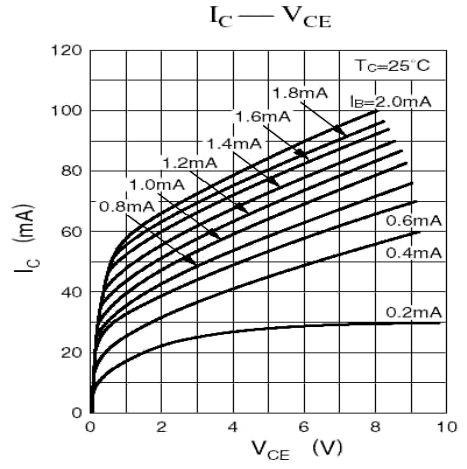
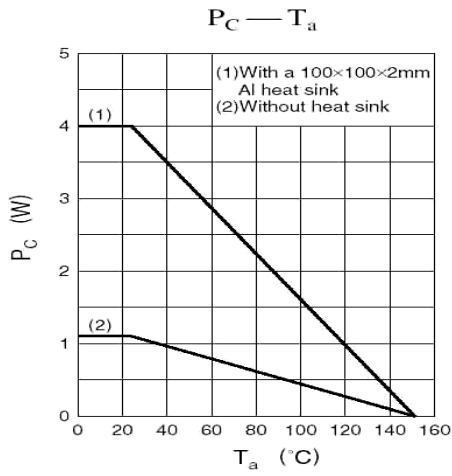
\* 带铝散热片尺寸：100×100×20mm。

\* With a 100×100×20mm Al heat sink.

**电性能参数 / Electrical Characteristics(Ta=25°C)**

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Emitter to Base Breakdown Voltage	V <sub>EBO</sub>	I <sub>E</sub> =0.1mA I <sub>C</sub> =0	7.0			V
Collector Cut-Off Current	I <sub>CEO</sub>	V <sub>CE</sub> =250V I <sub>B</sub> =0			100	μA
DC Current Gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =20V I <sub>C</sub> =40mA	40		200	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =50V I <sub>C</sub> =5.0mA	30			
Collector to Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =50mA I <sub>B</sub> =5.0mA			1.2	V
Base to Emitter Voltage	V <sub>BE</sub>	V <sub>CE</sub> =20V I <sub>C</sub> =40mA			1.2	V
Transition Frequency	f <sub>T</sub>	V <sub>CB</sub> =10V I <sub>C</sub> =10mA		100		MHz
Reverse Transfer Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =50V I <sub>E</sub> =0 f=1.0MHz		3.0	4.5	pF

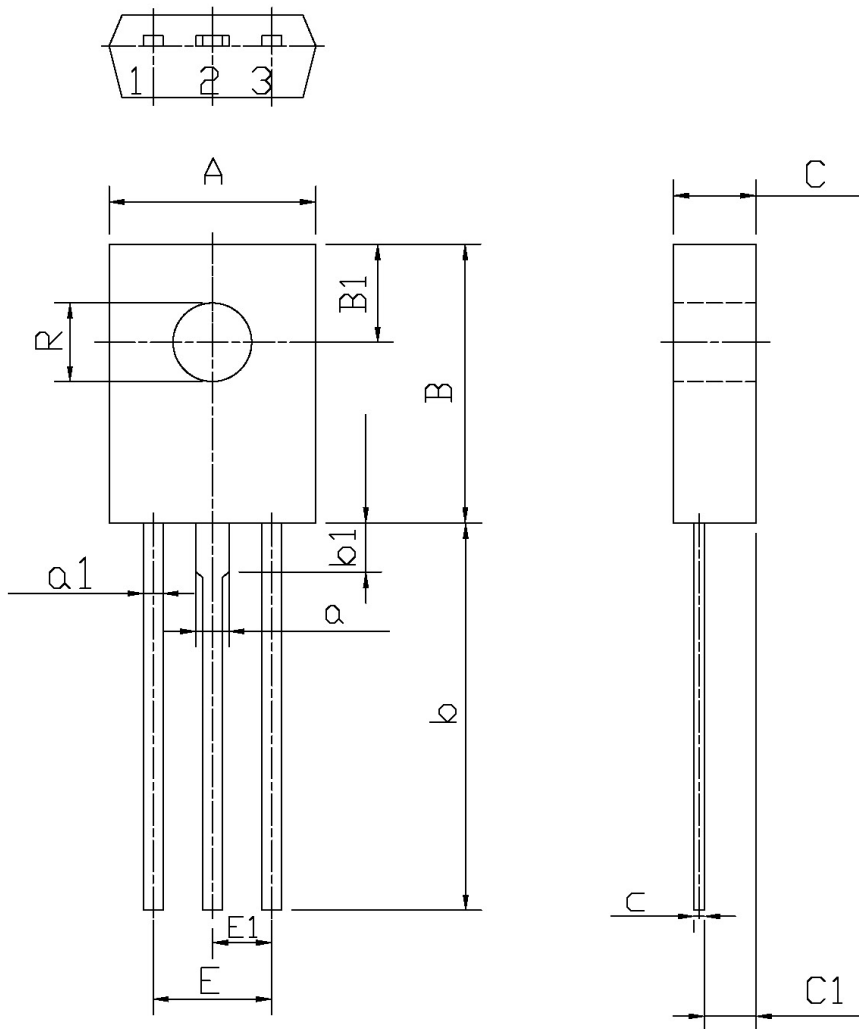
电参数曲线图 / Electrical Characteristic Curve



外形尺寸图 / Package Dimensions

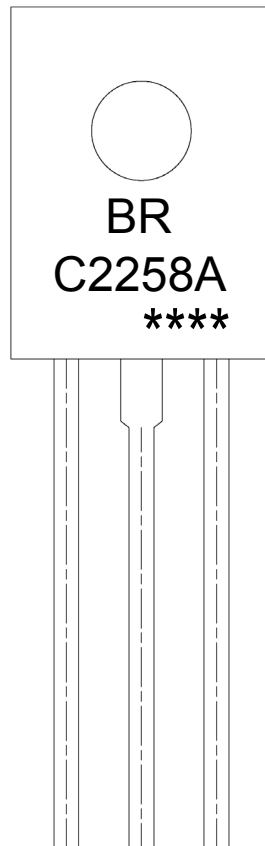
T0-126F

单位: mm



Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	7.8	8.2	a1	0.66	0.86
B	10.8	11.2	E	4.4	4.8
B1	3.8	4.2	C	3.1	3.3
R	2.95	3.15	C1	1.9	2.1
b	14	16	c	0.3	0.6
b1	1.9		a	1.27	
E1	2.1	2.5			

印章说明 / Marking Instructions



说明：

BR： 为公司代码

C2258A： 为型号代码

\*\*\*\*： 为生产批号代码，随生产批号变化。

Note:

BR: Company Code

C2258A: Product Type.

\*\*\*\*: Lot No. Code, code change with Lot No.

**波峰焊温度曲线图(无铅) / Temperature Profile for Dip Soldering(Pb-Free)**



说明：

- 1、预热温度 25 ~ 150°C，时间 60 ~ 90sec;
- 2、峰值温度 255±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

**耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions**

温度：270±5°C

时间：10±1 sec.

Temp.:270±5°C

Time:10±1 sec

**包装规格 / Packaging SPEC.**

散件包装 / BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-126/F	500	6	3,000	5	15,000	135×190	237×172×102	560×245×195

套管包装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-126/F	65	26	1,690	5	8,450	532×31×5.6	555×164×50	575×290×180

**使用说明 / Notices**